Inclosure Material:

Diode Semiconductor Device - Page 1 of 1



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Glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.107 inches	
Joint Electronic Devi	ce Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed ca	se and quality assurance level tx
Semiconductor Mater	ial:
Silicon	
Voltage Rating In Vol	ts Per Characteristic:
9.0 regulator voltage	
Voltage Tolerance In	Percent:
-5.0/+5.0	
Current Rating Per C	naracteristic:
7.50 milliamperes all p	rimaries horsepower metric and 50.00 milliamperes repetitive peak forward current
Power Rating Per Cha	aracteristic:
500.0 milliwatts small-s	ignal input power, common-collector preset
Maximum Operating	Fempurature Per Measurement Point:
175.0 degrees celsius	ambient air
Test Data Document:	
81349-mil-s-19500 spe	cification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes com	nercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and per	ormance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Q	uantity:
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/156	government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	